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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	3KB (2K x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	73 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c58b-04i-so

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

NOTES:

#### CONFIGURATION WORD FOR PIC16C54/C55/C56/C57 **REGISTER 9-2:**

—	—	—	—	—	—	—	—	CP	WDTE	FOSC1	FOSC0
bit 11											bit 0
bit 11-4:	Unimple	emented:	Read as '	0'							
bit 3:	<b>CP:</b> Code protection bit. 1 = Code protection off 0 = Code protection on										
bit 2:	WDTE:	Watchdog	timer ena	ble bit							
	1 = WD7	T enabled									
	0 = VVD	I disabled			. (2)						
bit 1-0:	FOSC1:	FOSC0: (	Oscillator s	election b	oits <sup>(2)</sup>						
	00 = L	P oscillato	or								
	01 = X	I oscillato	or								
	$10 = \Pi$	C oscillat	) or								
	TT = K		JI								
Note 1:	Refer to	the PIC16	C5X Prog	ramming	Specificat	ions (Liter	ature Nun	nber DS30	0190) to d	etermine h	now to
	access th	he configu	ration wor	d.							
2:	PIC16LV	/54A supp	orts XT, R	C and LP	oscillator	only.					
L a sua a du											

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, re	ad as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

# PIC16C5X

RLF	Rotate Left f through Carry								
Syntax:	[ <i>label</i> ] RLF f,d								
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$								
Operation:	See description below								
Status Affected:	С								
Encoding:	0011	. 01	df	ffff					
Description:	The contents of register 'f' are rotated one bit to the left through the Carry Flag (STATUS<0>). If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is stored back in register 'f'.								
Words:	1								
Cycles:	1								
Example:	RLF	REG	£1,0						
Before Instru REG1 C After Instruct	ction = = ion	1110 0	0110	0					
REG1	=	1110	0110	C					
W	=	1100	1100	C					
С	=	1							

RRF	Rotate Right f through Carry								
Syntax:	[ <i>label</i> ] RRF f,d								
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$								
Operation:	See description below								
Status Affected:	С								
Encoding:	0011 00df ffff								
Description:	The contents of register 'f' are rotated one bit to the right through the Carry Flag (STATUS<0>). If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f' C register 'f'								
Words:	1								
Cycles:	1								
Example:	RRF REG1,0								
Before Instru REG1 C	uction = 1110 0110 = 0								
REG1	= 1110 0110								
W C	= 0111 0011 = 0								

SLEEP	Enter SLEEP Mode							
Syntax:	[label]	SLEEP						
Operands:	None							
Operation:	00h $\rightarrow$ WDT; 0 $\rightarrow$ WDT prescaler; if assigned 1 $\rightarrow$ TO; 0 $\rightarrow$ PD							
Status Affected:	TO, PD							
Encoding:	0000 0000 0011							
Description:	Time-out status bit (TO) is set. The power-down status bit (PD) is cleared. The WDT and its pres- caler are cleared. The processor is put into SLEEP mode with the oscillator stopped. See section on SLEEP for more							
Words:	1							
Cycles:	1							
Example:	SLEEP							

## PIC16C5X

XORLW Exclusive OR literal with W								
Syntax:	[ <i>label</i> ]	XORLW	k					
Operands:	$0 \le k \le 255$							
Operation:	(W) .XOR. $k \rightarrow (W)$							
Status Affected:	Z							
Encoding:	1111	kkkk	kkkk					
Description:	The contents of the W register are XOR'ed with the eight bit literal 'k'. The result is placed in the W regis- ter.							
Words:	1							
Cycles:	1							
Example:	XORLW	0xAF						
Before Instruction W = 0xB5 After Instruction W = 0x1A								

XORWF	Exclusive OR W with f						
Syntax:	[ label ]	XORWF	f,d				
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$						
Operation:	(W) .XC	$DR.(f) \to (c)$	lest)				
Status Affected:	Z						
Encoding:	coding: 0001 10df ffff						
Description:	Exclusive OR the contents of the W register with register 'f'. If 'd' is 0 the result is stored in the W regis- ter. If 'd' is 1 the result is stored back in register 'f'.						
Words:	1						
Cycles:	1						
Example	XORWF	REG,1					
Before Instru							
REG = 0xAF							
W = 0xB5							
After Instruct	ion						
REG	=	0x1A					
W	= (	0xB5					

#### 11.13 PICDEM 3 Low Cost PIC16CXXX Demonstration Board

The PICDEM 3 demonstration board is a simple demonstration board that supports the PIC16C923 and PIC16C924 in the PLCC package. It will also support future 44-pin PLCC microcontrollers with an LCD Module. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 3 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer with an adapter socket, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 3 demonstration board to test firmware. A prototype area has been provided to the user for adding hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a thermistor and separate headers for connection to an external LCD module and a keypad. Also provided on the PICDEM 3 demonstration board is a LCD panel, with 4 commons and 12 segments, that is capable of displaying time, temperature and day of the week. The PICDEM 3 demonstration board provides an additional RS-232 interface and Windows software for showing the demultiplexed LCD signals on a PC. A simple serial interface allows the user to construct a hardware demultiplexer for the LCD signals.

#### 11.14 PICDEM 17 Demonstration Board

The PICDEM 17 demonstration board is an evaluation board that demonstrates the capabilities of several Microchip microcontrollers, including PIC17C752, PIC17C756A, PIC17C762 and PIC17C766. All necessary hardware is included to run basic demo programs, which are supplied on a 3.5-inch disk. A programmed sample is included and the user may erase it and program it with the other sample programs using the PRO MATE II device programmer, or the PICSTART Plus development programmer, and easily debug and test the sample code. In addition, the PICDEM 17 demonstration board supports downloading of programs to and executing out of external FLASH memory on board. The PICDEM 17 demonstration board is also usable with the MPLAB ICE in-circuit emulator, or the PICMASTER emulator and all of the sample programs can be run and modified using either emulator. Additionally, a generous prototype area is available for user hardware.

#### 11.15 KEELOQ Evaluation and Programming Tools

KEELOQ evaluation and programming tools support Microchip's HCS Secure Data Products. The HCS evaluation kit includes a LCD display to show changing codes, a decoder to decode transmissions and a programming interface to program test transmitters.

### 13.0 ELECTRICAL CHARACTERISTICS - PIC16CR54A

#### Absolute Maximum Ratings(†)

Ambient Temperature under bias	55°C to +125°C
Storage Temperature	65°C to +150°C
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss <sup>(1)</sup>	0 to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation <sup>(2)</sup>	
Max. current out of Vss pin	150 mA
Max. current into Vod pin	50 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iık (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (V0 < 0 or V0 > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA or B)	40 mA
Max. output current sunk by a single I/O port (PORTA or B)	50 mA

- **Note 1:** Voltage spikes below Vss at the  $\overline{\text{MCLR}}$  pin, inducing currents greater than 80 mA may cause latch-up. Thus, a series resistor of 50 to 100  $\Omega$  should be used when applying a low level to the  $\overline{\text{MCLR}}$  pin rather than pulling this pin directly to Vss.
  - **2:** Power Dissipation is calculated as follows: PDIS = VDD x {IDD  $\sum$  IOH} +  $\sum$  {(VDD-VOH) x IOH} +  $\sum$ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

#### 13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)			Standa Opera	ard Oper ting Tem	ating C	ondition 0° -40°	s (unless otherwise specified) $C \le TA \le +70^{\circ}C$ for commercial $C \le TA \le +85^{\circ}C$ for industrial
PIC16CR54A-04, 10, 20 PIC16CR54A-04I, 10I, 20I (Commercial, Industrial)			Standa Opera	ard Oper ting Temp	erating C	ondition 0° –40°	s (unless otherwise specified) $C \le TA \le +70^{\circ}C$ for commercial $C \le TA \le +85^{\circ}C$ for industrial
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
	IPD	Power-down Current <sup>(2)</sup>					
D006		PIC16LCR54A-Commercial		1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled
D006A		PIC16CR54A-Commercial		1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled
D007		PIC16LCR54A-Industrial	 	1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled
D007A		PIC16CR54A-Industrial		1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled

Legend: Rows with standard voltage device data only are shaded for improved readability.

- \* These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .

# PIC16C5X











#### FIGURE 14-22: PORTA, B AND C IOL vs. VoL, VDD = 5 V



#### 15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

PIC16I	C54A-04F	•	Stand	, ard One	ratino	, Condi	tions (unless otherwise specified)	
(Exten	ded)	-	Operat	ting Terr	perati	ure	$-40^{\circ}C \le TA \le +125^{\circ}C$ for extended	
PIC16C (Exten	<b>54A-04E,</b> ded)	10E, 20E	Standa Operat	Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended				
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
	Vdd	Supply Voltage						
D001		PIC16LC54A	3.0 2.5		6.25 6.25	V V	XT and RC modes LP mode	
D001A		PIC16C54A	3.5 4.5		5.5 5.5	V V	RC and XT modes HS mode	
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>		1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	-	Vss	_	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	—	V/ms	See Section 5.1 for details on Power-on Reset	
	IDD	Supply Current <sup>(2)</sup>						
D010		PIC16LC54A	-	0.5	25	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes	
			-	11	27	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Commercial	
				11	35	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Industrial	
			—	11	37	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Extended	
D010A		PIC16C54A	—	1.8	3.3	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC <sup>(3)</sup> and XT modes	
			-	4.8	10	mA	Fosc = 10 MHz, VDD = 5.5V, HS mode	
			-	9.0	20	mA	Fosc = 20 MHz, VDD = 5.5V, HS mode	

Legend: Rows with standard voltage device data only are shaded for improved readability.

- \* These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

#### 15.3 DC Characteristics: PIC16LV54A-02 (Commercial) PIC16LV54A-02I (Industrial)

PIC16LV54A-02 PIC16LV54A-02I (Commercial, Industrial)				$\begin{array}{llllllllllllllllllllllllllllllllllll$				
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
D001	Vdd	Supply Voltage RC and XT modes	2.0	_	3.8	V		
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>	—	1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	-	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	—	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	<b>Supply Current<sup>(2)</sup></b> RC <sup>(3)</sup> and XT modes LP mode, Commercial LP mode, Industrial		0.5 11 14	 27 35	mA μA μA	Fosc = 2.0 MHz, VDD = 3.0V Fosc = 32 kHz, VDD = 2.5V WDT disabled Fosc = 32 kHz, VDD = 2.5V WDT disabled	
D020	IPD	<b>Power-down Current<sup>(2,4)</sup></b> Commercial Commercial Industrial Industrial		2.5 0.25 3.5 0.3	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled	

These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.
  - 4: The oscillator start-up time can be as much as 8 seconds for XT and LP oscillator selection on wake-up from SLEEP mode or during initial power-up.

#### 15.6 Timing Diagrams and Specifications

#### FIGURE 15-2: EXTERNAL CLOCK TIMING - PIC16C54A



TABLE 15-1:	<b>EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A</b>

AC Chara	acteristics							
Param No.	Symbol	Characteristic Min Typ† Max Units Conditions						
	Fosc	External CLKIN Fre-	DC		4.0	MHz	XT OSC mode	
		quency <sup>(1)</sup>	DC	—	2.0	MHz	XT osc mode (PIC16LV54A)	
			DC	—	4.0	MHz	HS osc mode (04)	
			DC	—	10	MHz	HS osc mode (10)	
			DC	—	20	MHz	HS osc mode (20)	
			DC	—	200	kHz	LP osc mode	
		Oscillator Frequency <sup>(1)</sup>	DC	_	4.0	MHz	RC osc mode	
			DC	—	2.0	MHz	RC osc mode (PIC16LV54A)	
			0.1	—	4.0	MHz	XT osc mode	
			0.1	—	2.0	MHz	XT osc mode (PIC16LV54A)	
			4.0	—	4.0	MHz	HS osc mode (04)	
			4.0	—	10	MHz	HS osc mode (10)	
			4.0	—	20	MHz	HS osc mode (20)	
			5.0		200	kHz	LP osc mode	

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
  - Instruction cycle period (TcY) equals four times the input oscillator time base period.



#### TABLE 15-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54A

AC Characteristics		$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \ \ for \ commercial \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \ \ for \ industrial \\ -20^{\circ}C \leq TA \leq +85^{\circ}C \ \ for \ industrial \ -PIC16LV54A-02I \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \ \ for \ extended \\ \end{array} $					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	
10	TosH2ckL	OSC1↑ to CLKOUT↓ <sup>(1)</sup>		15	30**	ns	
11	TosH2ckH	OSC1↑ to CLKOUT↑ <sup>(1)</sup>		15	30**	ns	
12	TckR	CLKOUT rise time <sup>(1)</sup>	—	5.0	15**	ns	
13	TckF	CLKOUT fall time <sup>(1)</sup>		5.0	15**	ns	
14	TckL2ioV	CLKOUT↓ to Port out valid <sup>(1)</sup>		—	40**	ns	
15	TioV2ckH	Port in valid before CLKOUT↑ <sup>(1)</sup>	0.25 TCY+30*	_	_	ns	
16	TckH2iol	Port in hold after CLKOUT <sup>(1)</sup>	0*	—	_	ns	
17	TosH2ioV	OSC1 <sup>↑</sup> (Q1 cycle) to Port out valid <sup>(2)</sup>	—	_	100*	ns	
18	TosH2iol	OSC1 <sup>↑</sup> (Q2 cycle) to Port input invalid (I/O in hold time)	TBD		_	ns	
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	_	ns	
20	TioR	Port output rise time <sup>(2)</sup>	—	10	25**	ns	
21	TioF	Port output fall time <sup>(2)</sup>		10	25**	ns	

\* These parameters are characterized but not tested.

\*\* These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

**Note 1:** Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 15-1 for load conditions.

#### 17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial) PIC16C5X PIC16CR5X (Commercial, Industrial)							
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units Conditions			Conditions	
	Vdd	Supply Voltage					
D001		PIC16LC5X	2.5 2.7 2.5		5.5 5.5 5.5	V V V	$\begin{array}{l} -40^{\circ}C \leq TA \leq +\ 85^{\circ}C,\ 16LCR5X \\ -40^{\circ}C \leq TA \leq 0^{\circ}C,\ 16LC5X \\ 0^{\circ}C \leq TA \leq +\ 85^{\circ}C\ 16LC5X \end{array}$
D001A		PIC16C5X	3.0 4.5		5.5 5.5	V V	RC, XT, LP and HS mode from 0 - 10 MHz from 10 - 20 MHz
D002	Vdr	RAM Data Retention Volt- age <sup>(1)</sup>	-	1.5*	-	V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	_	V/ms	See Section 5.1 for details on Power-on Reset

Legend: Rows with standard voltage device data only are shaded for improved readability.

\* These parameters are characterized but not tested.

- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k $\Omega$ .



TΔRI F 17-2·	CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X PIC16CR5X

AC Characteristics		$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array}$					
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	
10	TosH2ckL	OSC1↑ to CLKOUT↓ <sup>(1)</sup>		15	30**	ns	
11	TosH2ckH	OSC1↑ to CLKOUT↑ <sup>(1)</sup>	—	15	30**	ns	
12	TckR	CLKOUT rise time <sup>(1)</sup>	—	5.0	15**	ns	
13	TckF	CLKOUT fall time <sup>(1)</sup>	—	5.0	15**	ns	
14	TckL2ioV	CLKOUT↓ to Port out valid <sup>(1)</sup>	—	_	40**	ns	
15	TioV2ckH	Port in valid before CLKOUT <sup>(1)</sup>	0.25 TCY+30*	_	—	ns	
16	TckH2iol	Port in hold after CLKOUT <sup>(1)</sup>	0*	_	—	ns	
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid <sup>(2)</sup>	—	_	100*	ns	
18	TosH2iol	OSC1 <sup>↑</sup> (Q2 cycle) to Port input invalid (I/O in hold time)	TBD		—	ns	
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns	
20	TioR	Port output rise time <sup>(2)</sup>	—	10	25**	ns	
21	TioF	Port output fall time <sup>(2)</sup>	—	10	25**	ns	

\* These parameters are characterized but not tested.

\*\* These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

**2:** Refer to Figure 17-5 for load conditions.

### 19.0 ELECTRICAL CHARACTERISTICS - PIC16LC54C 40MHz

#### Absolute Maximum Ratings<sup>(†)</sup>

Ambient temperature under bias	–55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to VSS	0 to +7.5V
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	–0.6V to (VDD + 0.6V)
Total power dissipation <sup>(1)</sup>	
Max. current out of Vss pin	
Max. current into Vod pin	
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, IIK (VI < 0 or VI > VDD)	±20 mA
Output clamp current, Iок (Vo < 0 or Vo > Voo)	±20 mA
Max. output current sunk by any I/O pin	
Max. output current sourced by any I/O pin	
Max. output current sourced by a single I/O (Port A, B or C)	
Max. output current sunk by a single I/O (Port A, B or C)	
<b>Note 1:</b> Power dissipation is calculated as follows: Pdis = VDD x {IDD - $\sum$ IOH} + $\sum$ {(VI	ор-Voн) x Ioн} + ∑(Vol x Iol)

**†** NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.



#### FIGURE 19-5: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X-40

#### TABLE 19-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X-40

AC Charac	teristics	Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial)Operating Voltage VDD range is described in Section 19.1.					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
30	TmcL	MCLR Pulse Width (low)	1000*		_	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns	

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

#### FIGURE 20-9: IOL vs. VOL, VDD = 5 V



### w

W Register	
Value on reset	20
Wake-up from SLEEP	19, 47
Watchdog Timer (WDT)	43, 46
Period	
Programming Considerations	
Register values on reset	
WWW, On-Line Support	3
X	
XORLW	60
XORWF	60
Z	
Zero (Z) bit	9, 29

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